

<b>Notice of References Cited</b>	Application/Control No. 10/517,728	Applicant(s)/Patent Under Reexamination WAGER ET AL.	
	Examiner Thanh-Truc Trinh	Art Unit 1753	Page 1 of 1

**U.S. PATENT DOCUMENTS**

*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Name	Classification
*	A	US-4,492,811	01-1985	Switzer, Jay A.	136/255
*	B	US-5,286,306	02-1994	Menezes, Shalini	136/249
*	C	US-6,043,427	03-2000	Nishimoto, Tomonori	136/258
	D	US-			
	E	US-			
	F	US-			
	G	US-			
	H	US-			
	I	US-			
	J	US-			
	K	US-			
	L	US-			
	M	US-			

**FOREIGN PATENT DOCUMENTS**

*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Country	Name	Classification
	N					
	O					
	P					
	Q					
	R					
	S					
	T					

**NON-PATENT DOCUMENTS**

*		Include as applicable: Author, Title Date, Publisher, Edition or Volume, Pertinent Pages)
	U	Hasan et al., "The optical and electrical properties of copper indium di-selenide thin films", Optical Materials, Volume 14, Issue 4, pages 329-336, August 2000.
	V	Zhang et al., "Sulfur p-band hole generation in beta-BaCu2S2. Synthesis of metallic KxB1-xCu2S2 from molten mixed K-Ba polysulfide salts", Journal of Alloys and Compounds 236 (1996) 1-5.
	W	
	X	

\*A copy of this reference is not being furnished with this Office action. (See MPEP § 707.05(a).)  
Dates in MM-YYYY format are publication dates. Classifications may be US or foreign.